

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	8792	( top\$1gate\$2 top adj gate\$2 non\$1inverted adj gate)	US-PGPUB; USPAT	OR	ON	2007/02/14 20:44
L2	65114	(semiconductor) with (crystal crystalline single adj crystal)	US-PGPUB; USPAT	OR	ON	2007/02/14 20:44
L3	42726	((base underl\$5 undercoat\$4) near2 (non\$1uniform thick\$4))	US-PGPUB; USPAT	OR	ON	2007/02/14 20:14
L4	160	1 and 2 and 3	US-PGPUB; USPAT	OR	ON	2007/02/14 20:14
L5	3197	((base underl\$5 undercoat\$4) near2 (non\$1uniform thick\$4 near5 thin\$4))	US-PGPUB; USPAT	OR	ON	2007/02/14 20:45
L6	7	1 and 2 and 5	US-PGPUB; USPAT	OR	ON	2007/02/14 20:46
L7	24	Kawasaki adj Ritsuko.in. and Kasahara adj Kenji .in. and Ohtani adj Hisashi.in.	US-PGPUB; USPAT	OR	ON	2007/02/14 20:16
L8	9	("5247190"   "5264072"   "5399502"   "5594569"   "5643826"   "5817548"   "5893730"   "5923962"   "6066516").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/02/14 20:37
L9	25	("6410368").URPN.	USPAT	OR	OFF	2007/02/14 20:39
L10	1157	( top\$1gate\$2 top adj gate\$2 non\$1inverted adj gate)	EPO; JPO; DERWENT	OR	ON	2007/02/14 20:44
L11	65534	(semiconductor) with (crystal crystalline single adj crystal)	EPO; JPO; DERWENT	OR	ON	2007/02/14 20:44
L12	940	((base underl\$5 undercoat\$4) near2 (non\$1uniform thick\$4 near5 thin\$4))	EPO; JPO; DERWENT	OR	ON	2007/02/14 20:45
L13	0	10 and 11 and 12	EPO; JPO; DERWENT	OR	ON	2007/02/14 20:45
L14	1	(base underl\$5 undercoat\$4)adj film and 10 and 11	EPO; JPO; DERWENT	OR	ON	2007/02/14 20:45
L15	633	((((pattern\$4 etch\$4 taper tapering tapered)near5(aluminum near2 oxide "Al.sub.2O.sub.3" aluminum adj nitride adj oxide "AlN.sub.xO.sub.1-x" nitride near2 aluminum "AlN.sub.x" AlSiON LaSiON ((aluminum) near2 (rare adj earth)) AlSiON LaSiON boron near2 nitride))near17(substrate translucent plastic quartz glass))	US-PGPUB; USPAT	OR	ON	2007/02/14 20:54
L16	4	1 and 2 and 15	US-PGPUB; USPAT	OR	ON	2007/02/14 20:47

## EAST Search History

L17	4	1 and 15	US-PGPUB; USPAT	OR	ON	2007/02/14 20:47
L18	167	15 and (lcd electroluminescent display\$2 soi silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj transistor\$2)	US-PGPUB; USPAT	OR	OFF	2007/02/14 20:54
L19	7651	257/72 257/347 257/353 438/151  438/149.ccls.	US-PGPUB; USPAT	OR	ON	2007/02/14 20:55
L20	9	15 and 19	US-PGPUB; USPAT	OR	ON	2007/02/14 20:53
L21	212	((pattern\$4 etch\$4 taper tapering tapered)near5(aluminum near2 oxide "Al.sub.2O.sub.3" aluminum adj nitride adj oxide "AlN.sub.xO. sub.1-x" nitride near2 aluminum "AlN.sub.x" AlSiON LaSiON ((aluminum) near2 (rare adj earth)) AlSiON LaSiON boron near2 nitride))near17(substrate translucent plastic quartz glass))	EPO; JPO; DERWENT	OR	ON	2007/02/14 20:55
L22	10	21 and (lcd electroluminescent display\$2 soi silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj transistor\$2)	EPO; JPO; DERWENT	OR	OFF	2007/02/14 20:54
L23	647	257/72 257/347 257/353 438/151  438/149.ccls.	EPO; JPO	OR	ON	2007/02/14 20:55
L24	0	21 and 23	EPO; JPO; DERWENT	OR	ON	2007/02/14 20:55
L25	0	12 and 23	EPO; JPO; DERWENT	OR	ON	2007/02/14 20:56